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HVD381B

Variable Capacitance Diode for VCO



ADE-208-1409 (Z)

Rev. 0 Apr. 2001

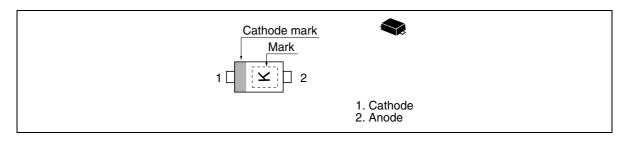
Features

- High capacitance ratio. (n = 1.65 min)
- Low series resistance. $(r_s = 0.5 \Omega \text{ max})$
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code	
HVD381B	K	SFP	

Pin Arrangement



HVD381B

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Reverse voltage	$V_{_{R}}$	15	V
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _{R1}	_	_	10	nA	V _R = 15 V
	I _{R2}	_	_	100		V _R = 15 V, Ta = 60°C
Capacitance	C ₁	10.0	_	11.0	pF	V _R = 1 V, f = 1 MHz
	C ₃	5.8	_	6.4		V _R = 3 V, f = 1 MHz
Capacitance ratio	n	1.65	_	_	_	C ₁ / C ₃
Series resistance	r _s	_	_	0.5	Ω	V _R = 1 V, f = 470 MHz

Note: Please do not use the soldering iron due to avoid high stress to the SFP package.

Main Characteristic

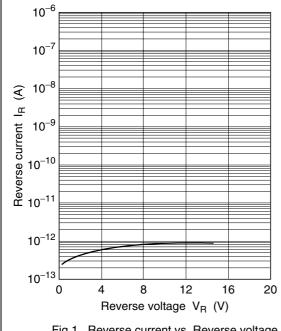


Fig.1 Reverse current vs. Reverse voltage

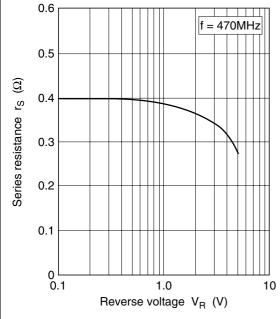


Fig.3 Series resistance vs. Reverse voltage

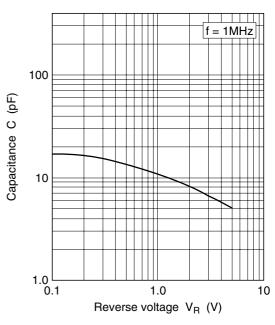
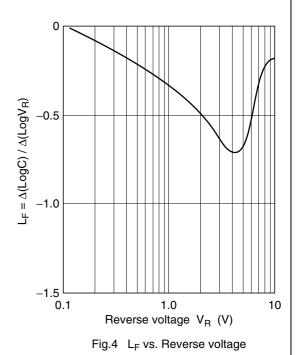
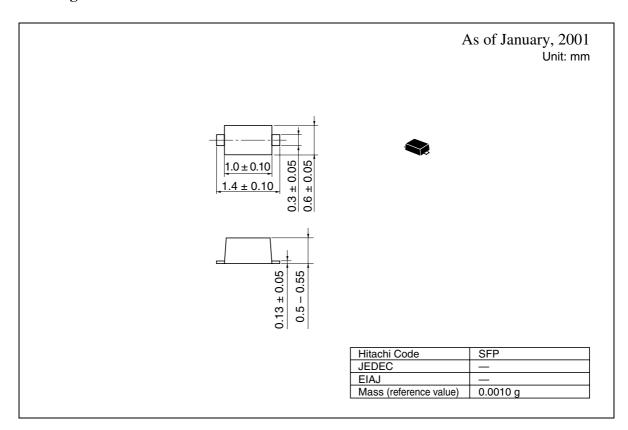


Fig.2 Capacitance vs. Reverse voltage



HVD381B

Package Dimensions



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